Product data sheet

1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a leadless medium power DFN2020MD-6 (SOT1220) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Logic-level compatible
- Trench MOSFET technology
- Side wettable flanks for optical solder inspection
- Small and leadless ultra thin SMD plastic package: 2 x 2 x 0.65 mm
- · Exposed drain pad for excellent thermal conduction

3. Applications

- Charging switch for portable devices
- DC-to-DC converters
- · Power management in battery-driven portable devices
- · Hard disk and computing power management

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	-30	V	
V _{GS}	gate-source voltage			-20	-	20	V	
I _D	drain current	V _{GS} = -10 V; T _{amb} = 25 °C; t ≤ 5 s	[1]	-	-	-9.5	Α	
Static characte	Static characteristics							
R _{DSon}	drain-source on-state resistance	$V_{GS} = -10 \text{ V}; I_D = -6.4 \text{ A}; T_j = 25 \text{ °C}$		-	24	28	mΩ	

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².



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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	D	drain	15/	D -
2	D	drain		
3	G	gate	2 5	G (FV)
4	S	source	3 8 4	s
5	D	drain	Transparent top view	017aaa094
6	D	drain	DFN2020MD-6	
7	D	drain	(SOT1220)	
8	S	source		

6. Ordering information

Table 3. Ordering information

Type number	nber Package						
	Name	Description	Version				
PMPB24EP		DFN2020MD-6: plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals	SOT1220				

7. Marking

Table 4. Marking codes

Type number	Marking code
PMPB24EP	6E

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8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{DS}	drain-source voltage	T _j = 25 °C		-	-30	V
V _{GS}	gate-source voltage			-20	20	V
I _D	drain current	V _{GS} = -10 V; T _{amb} = 25 °C; t ≤ 5 s	[1]	-	-9.5	А
		V _{GS} = -10 V; T _{amb} = 25 °C	[1]	-	-6.4	Α
		V _{GS} = -10 V; T _{amb} = 100 °C	[1]	-	-4.1	А
I _{DM}	peak drain current	T _{amb} = 25 °C; single pulse; t _p ≤ 10 μs		-	-26	Α
P _{tot}	total power dissipation	T _{amb} = 25 °C	[1]	-	1.8	W
		T _{amb} = 25 °C; t ≤ 5 s	[1]	-	3.9	W
		T _{sp} = 25 °C		-	15.6	W
T _j	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-drain	diode			'		
Is	source current	T _{amb} = 25 °C	[1]	-	-1.8	Α

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².

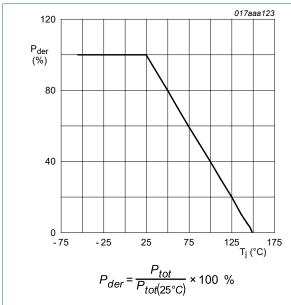


Fig. 1. Normalized total power dissipation as a function of junction temperature

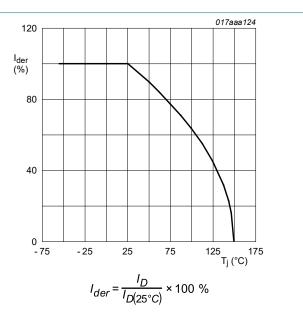


Fig. 2. Normalized continuous drain current as a function of junction temperature

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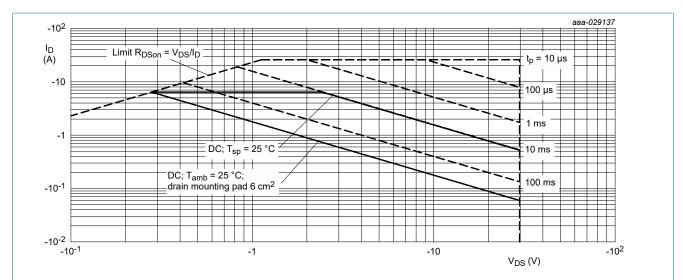


Fig. 3. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drain-source voltage

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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from	in free air	[1]	-	226	260	K/W
junction to	junction to ambient		[2]	-	60	70	K/W
		in free air; t ≤ 5 s	[2]	-	27	32	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	4	8	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².

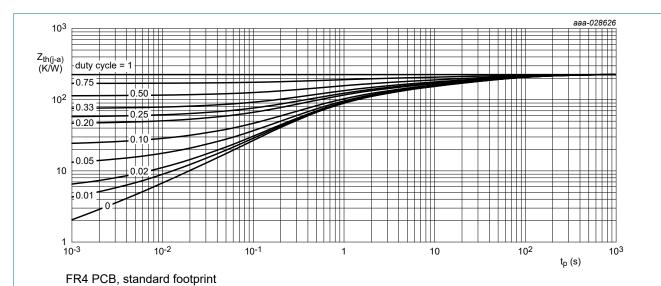


Fig. 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

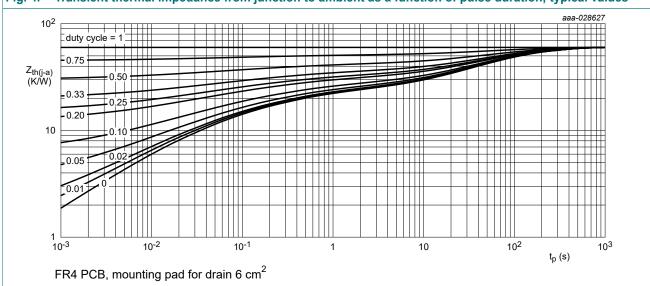


Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V _{(BR)DSS}	drain-source breakdown voltage	$I_D = -250 \mu A; V_{GS} = 0 V; T_j = 25 °C$	-30	-	-	V
V_{GSth}	gate-source threshold voltage	$I_D = -250 \mu A; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	-1	-1.5	-2.5	V
I _{DSS}	drain leakage current	$V_{DS} = -30 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	-1	μΑ
I _{GSS}	gate leakage current	V _{GS} = -20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-100	nA
		V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
R _{DSon}	drain-source on-state	V_{GS} = -10 V; I_D = -6.4 A; T_j = 25 °C	-	24	28	mΩ
	resistance	V_{GS} = -10 V; I_D = -6.4 A; T_j = 150 °C	-	37	43	mΩ
		$V_{GS} = -4.5 \text{ V}; I_D = -5.2 \text{ A}; T_j = 25 \text{ °C}$	-	32	42	mΩ
g _{fs}	forward transconductance	$V_{DS} = -10 \text{ V}; I_D = -6.4 \text{ A}; T_j = 25 \text{ °C}$	-	24	-	S
R_G	gate resistance	f = 1 MHz	-	7.8	-	Ω
Dynamic ch	aracteristics		'	'		
Q _{G(tot)}	total gate charge	$V_{DS} = -15 \text{ V}; I_D = -6.4 \text{ A}; V_{GS} = -10 \text{ V};$	-	19	28	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	3.5	-	nC
Q_{GD}	gate-drain charge		-	3.8	-	nC
C _{iss}	input capacitance	V _{DS} = -15 V; f = 1 MHz; V _{GS} = 0 V;	-	1069	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	121	-	pF
C _{rss}	reverse transfer capacitance		-	92	-	pF
t _{d(on)}	turn-on delay time	$V_{DS} = -15 \text{ V}; I_D = -6.4 \text{ A}; V_{GS} = -10 \text{ V};$	-	3	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	6	-	ns
t _{d(off)}	turn-off delay time		-	28	-	ns
t _f	fall time		-	14	-	ns
Source-drai	in diode		'			
V _{SD}	source-drain voltage	I _S = -1.8 A; V _{GS} = 0 V; T _i = 25 °C	-	-0.8	-1.2	V

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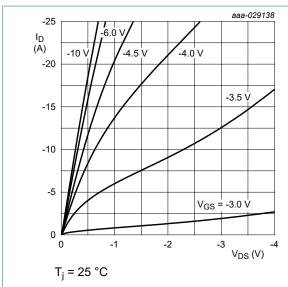


Fig. 6. Output characteristics: drain current as a function of drain-source voltage; typical values

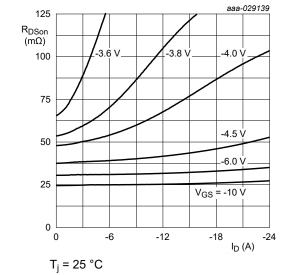


Fig. 8. Drain-source on-state resistance as a function of drain current; typical values

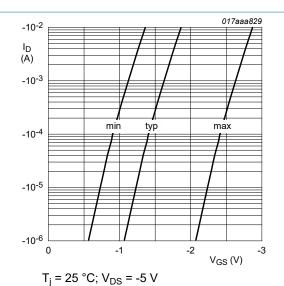


Fig. 7. Sub-threshold drain current as a function of gate-source voltage

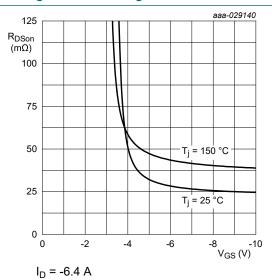


Fig. 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

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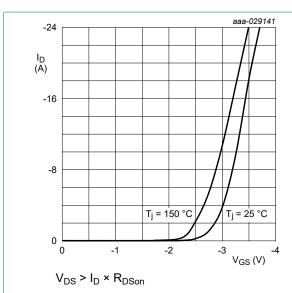


Fig. 10. Transfer characteristics: drain current as a function of gate-source voltage; typical values

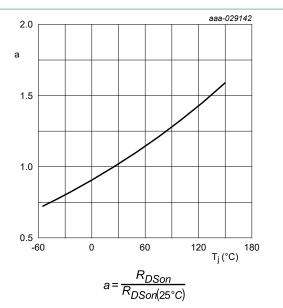


Fig. 11. Normalized drain-source on-state resistance as a function of junction temperature; typical values

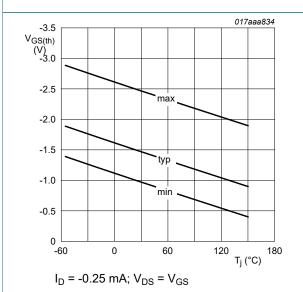


Fig. 12. Gate-source threshold voltage as a function of junction temperature

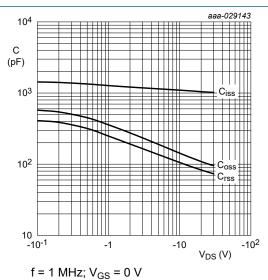


Fig. 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical

values

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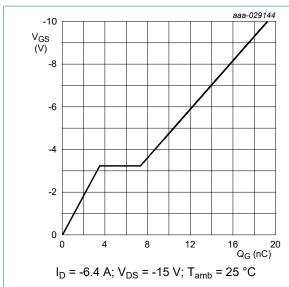


Fig. 14. Gate-source voltage as a function of gate charge; typical values

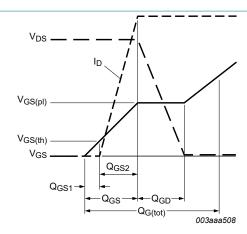


Fig. 15. Gate charge waveform definitions

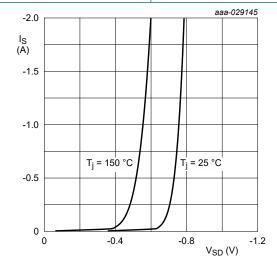
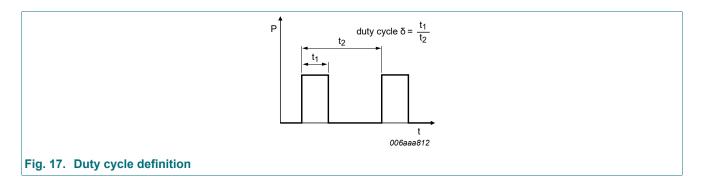


Fig. 16. Source current as a function of source-drain voltage; typical values

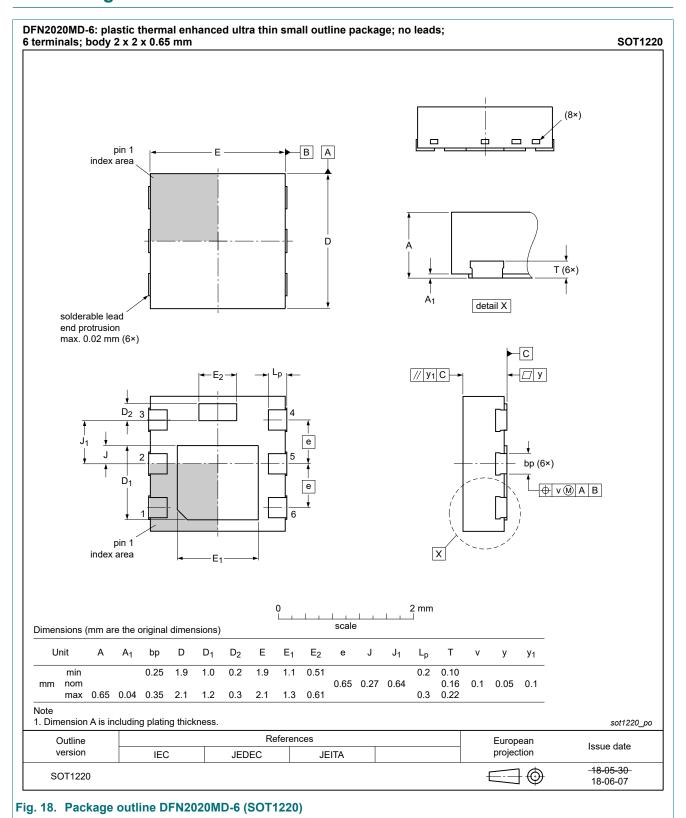
11. Test information

 $V_{GS} = 0 V$



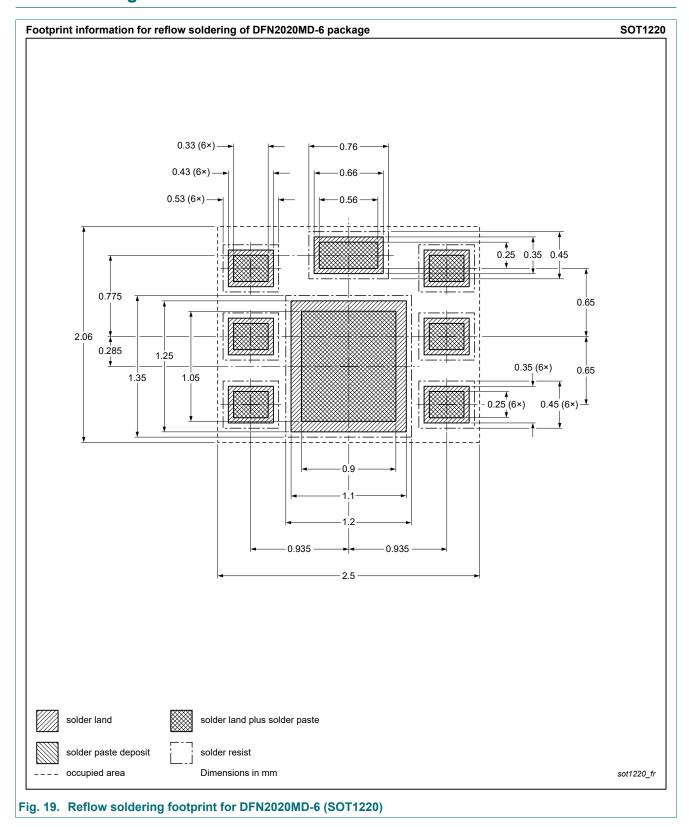
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12. Package outline



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13. Soldering



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14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMPB24EP v.1	20181022	Product data sheet	-	-

30 V, P-channel Trench MOSFET

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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	Features and benefits

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